

Low Capacitance Bidirectional TVS/ESD Protection Diode

DESCRIPTION

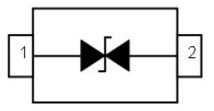
The GESD5B5CU is designed to protect voltage sensitive components from ESD and transient voltage events. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size, it is suited for use in cellular phones, portable devices, digital cameras, power supplies and many other portable applications where board space comes at a premium. Also because of its low capacitance, it is suited for use in high frequency designs such as USB 2.0 high speed, VGA, DVI, SDI and other high speed line applications.

This device has been specifically designed to protect sensitive components which are connected to data and transmission lines from overvoltage caused by ESD (electrostatic discharge), and EFT (electrical fast transients).

ORDERING INFORMATION

- ♦Device: GESD5B5CU
- ♦Package: SOD-523
- ♦Marking: LB
- ♦Material: Halogen free and RoHS compliant
- ♦Packing: Tape & Reel
- ♦Quantity per reel: 3,000pcs

PIN CONFIGURATION



FEATURES

- ♦IEC61000-4-2 (ESD) ±8kV (Contact), ±15kV (Air)
- ♦Peak power dissipation: 35W (8/20µs)
- ♦ Protects one I/O line
- \diamond Low clamping voltage
- ♦Working voltage: 5V
- ♦Low leakage current
- ♦Low capacitance

MACHANICAL DATA

- ♦SOD-523 package
- Terminals: Tin plated, solderable per MIL-STD-750, method 2026
- ♦Packaging: Tape and Reel
- ♦Reel size: 7 inch
- ♦Weight: 0.0018 gram (approx.)

APPLICATIONS

- ♦ High Speed Line: USB1.0/2.0, VGA, DVI, SDI
- ♦ Serial and Parallel Ports
- ♦Notebooks, Desktops, Servers
- ♦Projection TV
- ♦Cellular handsets and accessories

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- ♦Portable instrumentation
- ♦Peripherals

PACKAGE OUTLINE



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ABSOLUTE MAXIMUM RATING							
Symbol	Parameter	Value	Units				
V _{ESD}	ESD per IEC 61000-4-2 (Contact) ESD per IEC 61000-4-2 (Air)	±8 ±15	kV				
P _{PP}	Peak Pulse Power (8/20µs)	35	W				
Торт	Operating Temperature	-55~150	°C				
Тѕтс	Storage Temperature	-55~150	°C				

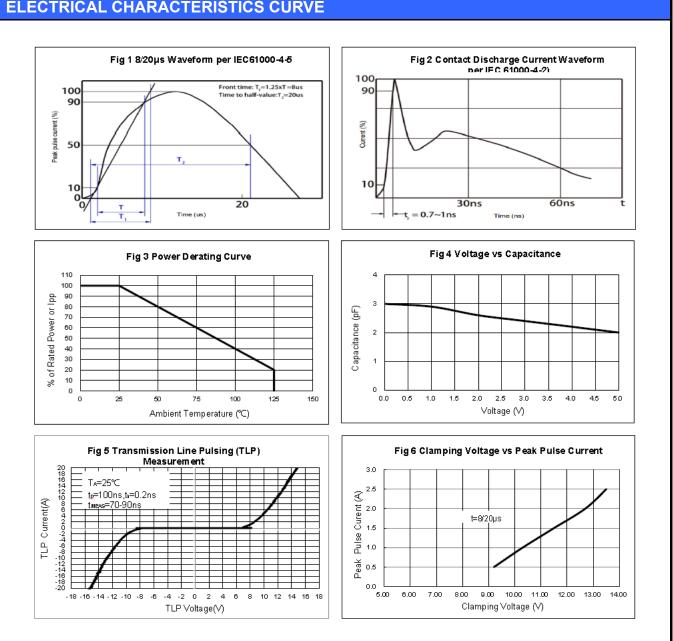
ELECTRICAL CHARACTERISTICS (Tamb=25°C)								
Symbol	Parameter	Test Condition	Min	Тур	Max	Units		
VRWM	Reverse Working Voltage				5.0	V		
VBR	Reverse Breakdown Voltage	I⊤ = 1mA	5.6		9.4	V		
I _R	Reverse Leakage Current	V _{RWM} = 5V			2.0	μA		
Vc	Clamping Voltage	I _{PP} = 1A, t _p = 8/20μs			10.5	V		
		I _{PP} = 2A, t _p = 8/20μs			14.0	V		
VCTLP	TLP Clamping Voltage	I _{PP} = 16A IEC61000-4-2 Level 4 equivalent (±8kV Contact, ±15kV Air)		14.5		V		
R _{DYN}	Dynamic Resistance	t _P = 100ns		0.3		Ω		
CJ	Junction Capacitance	V _R = 0V, f = 1MHz		3.0	3.5	pF		



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ELECTRICAL CHARACTERISTICS CURVE

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version: 02



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